INSTITUT FOR FYSIK OG ASTRONOMI DET NATURVIDENSKABELIGE FAKULTET AARHUS UNIVERSITET

# IFA – NYT UGE: 24

# Information fra administrationen

## Nye åbningstider i Informationen pr. 1. juli

Den 1. juli er Birthe Møller Christensen bevilget nedsat arbejdstid til 29,6 timer ugentligt. Det betyder at Informationen ikke mere har åbent hele dagen, men efter følgende plan:

MANDAG – TORSDAG	9.00-14.30
FREDAG	9.00-13.00
LUKKET I FROKOSTPAUSEN	12.15-13.00

### \*\*\*\*\*\*

## Sommerferiedækning i uge 30 i administrationen

**I uge 30** vil der ikke være sekretær bemanding i huset, da de alle har ønsket og fået bevilget ferie. Så hvis nogen af jer har brug for sekretærhjælp vil jeg bede jer planlægge det, således at arbejdet kan udføres før eller efter uge 30.

## \*\*\*\*\*\*\*

# Lukning af et herre- og et damebaderum i ugerne 31 og 32 (1524-120 og 1524-124).

Disse baderum kan ikke benyttes af **personalet** ved Fysik og Astronomi fra **den 24.** juli til den 9. august (begge dage inkl.)

I ugerne 31 og 32 er der henholdsvis Matematik Camp og Astronomi Camp, og vi har udlånt baderummene hertil.

Længere henne af gangen **1524-112 B** og **1524-112 C** samt ved lagerringen 1526-137 findes der alternative baderum til **damerne**, og **herrerne** kan benytte **1524-128 og 1524-132**.

\*\*\*\*\*\*

**Ruth Laursen** 

# INSTITUT FOR FYSIK OG ASTRONOMI AARHUS UNIVERSITET

Department of Physics and Astronomy, University of Aarhus



# Specialeeksamen

Emne:	Electronic Absorption Spectroscopy of GFP- and PYP- Chromophores in the Gas Phase
Tid og sted:	17. juni kl. 14:15 i 1525-323
Censor:	Theis I. Sølling
Vejleder:	Lars H. Andersen
Kandidat:	Dennis Bo Rahbek

# Naturvidenskabelig kvalifikationseksamen Forskeruddannelsens Del A

# FYSIK

Kandidat:	Maj-Britt S. Kirketerp
Vejleder:	Steen Brøndsted Nielsen
Ekstern censor:	Klaus Bechgaard
Intern censor:	Arne Nylandsted Larsen
Eksaminatorer:	Ulrik I. Uggerhøj og Karsten Riisager
Tid og sted:	15. juni kl. 14:15 i lokale 1525-323
Emne:	Photoexcitation of $\pi$ -conjugated molecular ions

# **Atomic and Molecular Physics Seminar**

Title:	Surface and Lattice Vibrational modes in Hydrogenated and Deuterated Polycrystalline Diamond
Speaker:	Roger Azria Université Paris-Sud, Orsay
Time:	Thursday 18 <sup>th</sup> June at 3:15 pm
Place:	Phys.Aud. 3 <sup>rd</sup> Floor Physics and Astronomy

## Abstract:

Diamond surfaces are of great interest due to their special properties of hardness, thermal and chemical stability, electronic properties and biocompatibility. Hydrogenated diamond surfaces may exhibit negative electron affinity making these surfaces good candidates for the realization of detectors.

I will report electron energy-loss spectra displaying elastic and inelastic excitation functions of lattice and surface vibrational modes for hydrogenated surfaces. These have been measured by high-resolution electron energy-loss (HREELS) spectroscopy for hydrogenated and deuterated polycrystalline diamond films.

Data show in particular that (i) vibrational excitation functions are strongly influenced by the density of states characterizing the local environment of the  $CH_x$  species for surface modes, with regard to stretching modes of  $sp^2$ - and  $sp^3$ - hybridised species and (ii) that for a given local environment the effect of an existing band gap - located above the vacuum level - on excitation functions associated with lattice modes depends on the number and depth of the layers involved in the vibrational spectra.

An unambiguous attribution of the different peaks which appear in the HREELS spectra will also be given.

# Coffee, tea and cake will be served at 3 pm

I have reworded the abstract a bit. Could you check that I have understood it correctly (especially point (ii))!

Energy loss spectra, elastic and inelastic excitation functions of lattice and surface vibrational modes have been measured by high-resolution electron energy-loss (HREELS) spectroscopy for hydrogenated and deuterated polycrystalline diamond films.

It is shown in particular that (i) vibrational excitation functions are strongly influenced by the density of states characterizing the CHx species local environment for surface modes, with regard to stretching modes of sp2- and sp3-hybridised species and (ii) that for a given local environment the effect of an existing band gap (located above the vacuum level) on excitation functions associated with lattice modes depends on the number and depth of the layers involved in the vibrational spectra.

An unambiguous attribution of the different peaks which appear in the HREELS spectra will also be given.

Looking forward very much to seeing you both!

Amicalement

David

Dear David,

The title of my seminar is "Density-of-States Effects on Surface and Lattice Vibrational modes in Hydrogenated and Deuterated Polycrystalline Diamond".

Energy loss spectra, elastic and inelastic excitation functions of lattice and surface vibrational modes have bean measured by high-resolution electron energy-loss (HREEL)spectroscopy for hydrogenated and deuterated polycrystalline diamond films.

It is shown in particular (i) that for surface modes, considering stretching modes of sp2 - and sp3 - hybridised CHx species vibrational excitation functions are strongly governed by the DOS characterizing the species local environment, (ii) that for a given local environment the effect of an existing band gap (located above vacuum

...,

level) on excitation functions associated with lattice modes depends on the number and depth of the vibrationally involved layers.

An unambiguously attribution of the different peaks which appear in the HREEL spectra is also proposed.



15. MAJ 2009

## Indvielse af Center for Scienceuddannelse (CSE)

Det Naturvidenskabelige Fakultet, Aarhus Universitet Bygning 1530, Vandrehallen og Aud. F 15. juni 2009 kl. 14.00 - 16.30

#### Program

#### 14.00 Velkomst og taler Dekan Erik Meineche Schmidt m.fl.

- 14.15 Præsentation af CSE Centerleder Michael E. Caspersen
- 14.30 Festforelæsning: Confessions of a converted lecturer Eric Mazur, Professor of Physics at Harvard University
- 15.30 Reception

#### Eric Mazur

Udover at være en fremragende forsker og underviser er Eric Mazur særdeles engageret og indflydelsesrig inden for educational research. Specielt har han formuleret og forfinet undervisningsprincippet "peer instruction" og den så-kaldte "clicker"-teknologi som understøtter denne undervisningsform.

#### Abstract

I thought I was a good teacher until I discovered my students were just memorizing information rather than learning to understand the material. Who was to blame? The students? The material? I will explain how I came to the agonizing conclusion that the culprit was neither of these. It was my teaching that caused students to fail! I will show how I have adjusted my approach to teaching and how it has improved my students' performance significantly.

#### Center for Scienceuddannelse (CSE)

Centeret er en nyetableret enhed til undervisningsudvikling ved Det Naturvidenskabelige Fakultet, AU.

Centeret skal styrke undervisning, uddannelse og uddannelsesmæssig infrastruktur i fag inden for det teknisknaturvidenskabelige område på universitetet, i gymnasiesektoren og i folkeskolen/på læreruddannelsen gennem forsknings- og udviklingsprojekter på lokalt, nationalt og internationalt plan.

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- Support af partnerskaber mellem læreruddannelsen og praktikskoler til fremme af en udviklingsorienteret læreruddannelse
- Tilbyde lærere deltagelse i skolelærerdage, som inspiration til undervisningen

Centeret samarbejder med tilsvarende enheder ved AU, i Danmark og internationalt. Læs mere om centeret på vores hjemmeside: <u>www.cse.au.dk</u>. © 2009. The American Astronomical Society. All rights reserved. Printed in the U.S.A.

### EXCITATION AND DAMPING OF *p*-MODE OSCILLATIONS OF α Cen B

 W. J. CHAPLIN<sup>1</sup>, G. HOUDEK<sup>2</sup>, Y. ELSWORTH<sup>1</sup>, R. NEW<sup>3</sup>, T. R. BEDDING<sup>4</sup>, AND H. KJELDSEN<sup>5</sup>
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#### ABSTRACT

This paper presents an analysis of observational data on the *p*-mode spectrum of the star  $\alpha$  Cen B, and a comparison with theoretical computations of the stochastic excitation and damping of the modes. We find that at frequencies  $\gtrsim 4500 \,\mu$ Hz, the model damping rates appear to be too weak to explain the observed shape of the power spectral density of  $\alpha$  Cen B. The conclusion rests on the assumption that most of the disagreement is due to problems modeling the damping rates, not the excitation rates, of the modes. This assumption is supported by a parallel analysis of BiSON Sun-as-a-star data, for which it is possible to use analysis of very long timeseries to place tight constraints on the assumption. The BiSON analysis shows that there is a similar high-frequency disagreement between theory and observation in the Sun. We demonstrate that by using suitable comparisons of theory and observation it is possible to make inference on the dependence of the *p*-mode linewidths on frequency, without directly measuring those linewidths, even though the  $\alpha$  Cen B dataset is only a few nights long. Use of independent measures from a previous study of the resulting calibrated linewidth curve looks similar to a frequency-scaled version of its solar cousin, with the scaling factor equal to the ratio of the respective acoustic cut-off frequencies of the two stars. The ratio of the frequencies at which the onset of high-frequency problems is seen in both stars is also given approximately by the same scaling factor.

Key words: methods: data analysis - stars: activity - stars: oscillations - Sun: activity - Sun: helioseismology

The Ages of Stars Proceedings IAU Symposium No. 258, 2008 E.E. Mamajek, D.R. Soderblom & R.F.G. Wyse, eds.

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# The Sun as a fundamental calibrator of stellar evolution

Jørgen Christensen-Dalsgaard

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**Abstract.** The Sun is unique amongst stars in having a precisely determined age which does not depend on the modelling of stellar evolution. Furthermore, other global properties of the Sun are known to much higher accuracy than for any other star. Also, helioseismology has provided detailed determination of the solar internal structure and rotation. As a result, the Sun plays a central role in the development and test of stellar modelling. Here I discuss solar modelling and its application to tests of asteroseismic techniques for stellar age determination.

**Keywords.** Sun: evolution, Sun: interior, Sun: helioseismology, Sun: fundamental parameters, stars: evolution, stars: interior, stars: oscillations, stars: fundamental parameters, asteroseismology

#### SIGNATURE OF DECONFINEMENT WITH SPIN-DOWN COMPRESSION IN COOLING HYBRID STARS

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<sup>1</sup> Department of Physics and Astronomy, University of Aarhus, Ny Munkegade, Bld. 1520, DK-8000 Aarhus C, Denmark <sup>2</sup> Department of Physics, San Diego State University, 5500 Campanile Dr, San Diego, CA 92182-1233, USA *Received 2007 December 21; accepted 2009 January 8; published 2009 March 20* 

#### ABSTRACT

The thermal evolution of neutron stars is coupled to their spin down and the resulting changes in structure and chemical composition. This coupling correlates stellar surface temperatures with rotational state as well as time. We report an extensive investigation of the coupling between spin down and cooling for hybrid stars which undergo a phase transition to deconfined quark matter at the high densities present in stars at low rotation frequencies. The thermal balance of neutron stars is re-analyzed to incorporate phase transitions and the related latent heat self-consistently, and numerical calculations are undertaken to simultaneously evolve the stellar structure and temperature distribution. We find that the changes in stellar structure and chemical composition with the introduction of a pure quark matter phase in the core delay the cooling and produce a period of increasing surface temperature for strongly superfluid stars of strong and intermediate magnetic field strength. The latent heat of deconfinement is found to reinforce this signature if quark matter is superfluid and it can dominate the thermal balance during the formation of a pure quark matter core. At other times, it is less important and does not significantly change the thermal evolution.

Key words: dense matter - equation of state - stars: neutron - stars: rotation

*Online-only material:* color figures



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Physics Letters B

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# On the macroscopic formation length for GeV photons

CERN NA63 Collaboration

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#### ABSTRACT

Experimental results for the radiative energy loss of 206 and 234 GeV electrons in 5–10  $\mu$ m thin Ta targets are presented. An increase in radiation emission probability at low photon energies compared to a 100  $\mu$ m thick target is observed. This increase is due to the formation length of the GeV photons exceeding the thickness of the thin foils, the so-called Ternovskii–Shul'ga–Fomin (TSF) effect. The formation length of GeV photons from a multi-hundred GeV projectile is through the TSF effect shown directly to be a factor 10<sup>10</sup> longer than their wavelength.

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Det naturvidenskabelige fakultet Aarhus Universitet

# OPSLAG

# NATURVIDENSKABELIG KVALIFIKATIONSEKSAMEN Ph.d.-UDDANNELSENS DEL A SOMMER 2009 NANOTEKNOLOGI

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29.05.2009

NAT-Studiekontoret

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# Spectrally narrow polarisation conversion in a slow-light photonic crystal waveguide

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A narrow-band (3 dB bandpass < 2 nm) transmission notch based on polarisation conversion within a SOI photonic crystal waveguide is demonstrated. Signal contrast between quasi- TE and TM eigenstates exceeding 40 dB is achieved. Further, multiple resonant wavelength coupling between the two eigenstates is also observed. [DOI: 10.2971/jeos.2009.09019]

Keywords: integrated optics, polarisation, SOI, silicon, photonics

## **1 INTRODUCTION**

Silicon-on-insulator (SOI) technology is the leading platform for integrated photonic and electro-optic circuits [1]. Of these, SOI photonic crystals are seen as a unique approach for practical engineering of highly dispersive compact components for a number of applications where manipulation of an optical field is required [2]–[6]. However, a significant technological challenge remains in fully understanding such properties within even the simplest components. The critical difference in polarisation transmission properties has generally driven a focus on fabricating single polarisation (quasi- TE) photonic chips, although more sophisticated designs enable consideration of both eigenstates [6, 7]. In order to better understand the polarisation properties of such simple crystal structures, we recently carried out a comprehensive evaluation of the polarisation properties of these linear waveguides and showed evidence of significant cross coupling across the entire transmission bands of both quasi- TE and TM (henceforth labeled simply TE and TM) eigenstates [8]. We also reported highly localized polarisation conversion at the TE transmission band edge, principally arising from resonant dispersion and beating demonstrated experimentally and through numerical simulation [8], raising some questions as to the exact definition of this edge. These properties, which were supported by numerical simulation, raise significant questions on the role of dispersion even within single TE polarisation components and necessitate a review of how these components are to be utilized. In this letter, we demonstrate how the dispersion within the TE bandgap can be used to create ultra-narrow polarisation conversion between TE and TM with a signal contrast ra-

Received February 26, 2008; published April 19, 2009

tio exceeding 40 dB within the bandgap away from the resonant edge. These results suggest that a more careful evaluation of the bandgap properties of such structures is necessary. By filtering the signal with polarisers narrowband notch filters can be made that are an alternative to cavity-based designs [9] with potential slow light applications. In several cases these filters may solve one of the other outstanding challenges of crystal waveguides, namely the design and fabrication of narrow-band optical add-drop filters.

## **2 WAVEGUIDE FABRICATION**

The waveguides were fabricated using a commercial SOI-wafer as platform. Electron-beam lithography (JEOL-JBX9300FS) and inductively coupled plasma (ICP) etching were applied to define the photonic crystal (PhC) structure and coupling elements into the 320 nm top silicon layer.

Figure 1 shows a scanning electron microscope (SEM) image of a typical fabricated crystal structure. Not shown are the adiabatically tapered straight waveguides from 4  $\mu$ m to 0.7  $\mu$ m which allow coupling into and out of the PhC waveguide. In order to couple light into the structures, lensed end fibres are used to focus light to a ~ 3  $\mu$ m spot onto the waveguide facet. From the SEM images we measured the triangular lattice constant (pitch),  $\Lambda = 370$  nm, the hole radius  $r = 125 \pm 5$  nm, which gives for this PhC  $r/\Lambda = 0.34$ , and the Si waveguide thickness, h = 320 nm. The PhC waveguide is created by re-



FIG. 1 Schematic of setup employed and SEM image of a 5  $\mu$ m photonic crystal waveguide inserted as the PhC. The actual sample used was 50  $\mu$ m in length but with identical crystal parameters. Also not shown because of size restraints in the imaging process is the SOI tapered input waveguides leading into the structure. PhC -photonic crystal; PC - polarisation controller; P - polariser; LF - lensed fibre; TL - tuneable laser; OSA - optical spectrum analyser.

moving a row of holes along the  $\Gamma$ -K direction. The length of the investigated PhC waveguides is 50  $\mu$ m.

## 3 ULTRANARROW FILTER OPERATION AND CHARACTERISATION

The setup for realising the filter is shown in Figure 1. It consists of the SOI input tapers and crystal waveguide, lensed fibres (LF) for coupling into the SOI tapers and polarisation controllers (PC) and polarisers (P) to allow both full control and monitoring of the polarisation states entering and leaving the device. A tuneable laser (TL) and optical spectrum analyser (OSA) are used to characterise the device.

The premise of the device operation is as follows: from our previous work it was shown that cross coupling between (quasi) TE and TM eigenstates within such photonic crystal waveguides is characterised by a regular beating across the entire telecommunications spectrum and beyond [8]. Such beating is not unexpected since it is identical to coupling between two otherwise orthogonal modes (non-quasi eigenstates) when scattering and/or waveguide asymmetry is present. This can be readily observed at long wavelengths where only TM light propagates but can also be observed within the band edge of the TE transmission pass band. The latter observation is particularly important since it raises practical issues regarding true all-TE only guidance, for example, as well as make uncertain the exact position of the transmission band edge. Such broadband beating is an indicator that the polarisation dispersion is largely material dispersion between air and the silicon across the entire length of the device possibly with some additional contribution from mixing due to excitation of leaky interface states at the ends of the crystal waveguide [10]. This interferogram is primarily determined by the SOI waveguide modal birefringence, B, arising from asymmetry of the structure where the phase change,  $\phi = 2\pi LB/\lambda$ , is over its entire length, *L*, of 2 mm. On the other hand, the 50  $\mu$ m crystal structure gives rise to very large, but narrowband, polarisation dispersion, which is related to the waveguide dispersion by the *Q* of the lattice structure (i.e.  $B_{crystal} \sim QB_{waveguide}$ ) as TE light approaches the TE band edge. The group velocity within a high Q "cavity" determines the slow light properties of the structure.

Although the TM light does experience some dispersion change within the TE bandgap it is small compared to that of the TE light approaching the bandgap defined in principle by the sharp TE transmission edge. This dispersion is significant even before the edge is reached - it is therefore not unreasonable to suppose that phase matching between the polarisation dispersion of the waveguide and the crystal is possible within the TE transmission window for a relatively narrow spectral range because of the large dispersion difference between the two modes involved (TE and TM) [11]. Preliminary observations and numerical simulation have confirmed this is possible [8]. In order to substantially increase the amount of narrow grating-assisted cross coupling between the two polarisation states for novel device purposes, the polarisation input must be optimised carefully. This can be done by initially optimising the bandgap by ensuring only TE light is launched through minimisation of the signal throughput within the TE bandgap. Then the laser and detection system is fixed at one wavelength near the transmission edge and small adjustments are made to the in-coupling polarisation in combination with larger changes to the relative phase of the TE and TM contributions using the polarisation controller at the input. After some adjustment the transmission level starts to drop, and after careful adjustment it is possible to reduce the transmission by more than 40 dB. These results demonstrate that it is possible to manipulate and enhance previous reports on such phenomena [8] to levels that make potentially useful devices.

## 4 RESULTS AND DISCUSSION

Figure 2 shows the optimised situation where a strong resonant notch ( $\sim 40$  dB signal contrast between quasi polarisation eigenstates) within the quasi TE transmission window at 1502 nm is observed. The 3 dB bandwidth is < 2 nm. The corresponding TM output profile, where the output polariser is rotated 90°, clearly shows that the TE rejected light has been converted to TM as predicted. Also observable in the TM spectra is an additional transmission loss at  $\sim 1497.5$  nm – how-



FIG. 2 Transmission spectra of quasi- TE and TM fields through the device. Narrow transmission gap is observed at 1502 nm for TE light. A corresponding rise in TM signal is seen.

ever, the signal level is too low to determine whether this has been converted to TE, although this seems likely.

From the interferogram observable at longer wavelengths, where  $\Delta \lambda \sim (1.4 - 2.0)$  nm, we estimate a birefringence of  $B_{waveguide} = \lambda^2/(L\Delta\lambda) \sim 0.56$ , which is large and arises mainly from the asymmetry of the structure. Depending on the dispersion of the crystal and the exact tuning of phase and amplitude with the input polarisation controller, it is possible to achieve phase matching conditions at other wavelengths than the one shown here. For example, the dispersion at 1502 nm is not particularly high compared to that approaching the edge - it is reasonable to assume that the measured crystal dispersion of these types of channels [12] for TE eigenstates, is sufficient for conversion of both TE and TM up to the edge and slightly beyond. The signal levels are low for the TM eigenstate in the optimised result above, where TE light beyond the edge is thought to be lost via various mechanisms including back reflection, cladding and lattice modes and some TM conversion. This can be increased by readjusting the input polarisation conditions to see if most of the TE light is coupled into TM whilst still retaining a strong transmission notch. The ability to do this is sensitive to the control over polarisation at both the input and output. Noticeably, we retained high TE transmission below the transmission edge that is the input polariser mostly allows TE through only. Signal transmission was optimised for TE at 1490 nm whilst at the same time the transmission notch is maintained at  $\sim 1502$ nm. Figure 3 shows the raw spectra obtained. A single-peak transmission notch remains although there is significant TM light present. The background signal is nearly uniform – below the band edge it resembles that of Figure 2 (with significant attenuation) whilst at longer wavelengths the signal has increased to comparable levels. The interferogram has disappeared and is replaced instead by a series of decreasing notches (pointed out by arrows on Figure 3), indicative of cross coupling with TE and the formation of additional Fano resonances [13]. The strength of these notches indicates inefficient coupling since TE polarisation propagation is generally



FIG. 3 Transmission resonant notch spectra optimised to have quasi- TE at wavelengths below and quasi- TM at wavelengths above the quasi- TE transmission band edge. Arrows point out additional resonant peaks.

forbidden in this region. Despite this, with the significantly smoother transmission signals across the whole spectrum it is now possible to observe multiple wavelength coupling spaced at intervals equal to the interferogram period. A more comprehensive measurement system based on this approach may provide a useful direct characterisation of the dispersion properties of the crystal structures.

The narrow polarisation resonances can be modelled by using the analogy with a simple coupler from classical integrated optics [11] where the two fundamental waveguide modes in adjacent waveguides are replaced with the two polarisation modes TE and TM in the same crystal waveguide. The orthogonality of the ideal eigenstates is broken by the asymmetry of the device enabling analogous beating to occur. However, despite the asymmetry, any analysis needs to consider a larger dispersion difference between the actual polarisation modes than normal modes which tend to have reduced dispersion difference. The resulting equations should be used in the opposite dispersion approximation (very high dispersion difference, similar to the asynchronous solution) compared to the usual case for classical waveguides (similar modes with small dispersion difference). If initially all the light is in quasi-TE, the dispersion is entirely linear, and the propagation losses (and in particular the large difference in propagation loss for TE and TM) are ignored the problem can be solved analytically [11] and one finds for the power coupled to TM:

$$P_{TM} = \frac{\sin^2\left(\sqrt{\nu^2 + \xi^2}\right)}{1 + \xi^2 / \nu^2}$$
(1)

where the normalised coupling length,  $\nu$ , and the normalised de-phasing parameter,  $\xi$ , are given by

$$\nu = \kappa L \quad ; \quad \tilde{\xi} = \Delta \beta \frac{L}{2}$$
 (2)

where *L* is the length of the waveguide. Since the difference in propagation constants,  $\Delta\beta$ , (and thereby  $\xi$ ) is very large and the coupling strength,  $\kappa$ , is moderate to large, this gives rise to a narrow sinc function as a function of *L* or wavelength (analogous equation). Due to the large dispersion and the large difference in loss for TE and TM the coupling profiles will generally be asymmetric with extremely suppressed or even absent side-modes for the sinc function, since the side-modes are more sensitive to de-phasing. In the realistic case there is of course some initial power in TM and a phase difference between the two modes. This is what determines the exact position and depth of the notch in TE (and peak in TM). However, the general equations cannot be solved analytically.

#### 5 CONCLUSIONS

By controlling the output polarisation we have been able to demonstrate a novel narrow band-pass filter with more than 40 dB signal contrast, which exploits the high dispersion available from the quasi- TE eigenstate of the crystal. The asymmetric dispersion that differentiates the transmission bands of TE and TM, essentially arising from Brewster scattering within the structure [8], potentially allows the generation and tuning of optical Fano-like resonances by adjusting the polarisation without directly invoking material nonlinearity. Such resonances can be exploited for slow light generation and applications. Careful phase matching with the TM eigenstate couples the light into the orthogonal polarisation – it is therefore a simple matter to filter out this light using an external polariser on the output. In more sophisticated designs such polarisers can be made onto the chip itself. Alternatively, the coupled light can be taken out and transported into alternative waveguides using appropriately designed couplers [13] or interference regions. Further, the bandwidth of the device can be tailored by tailoring the crystal properties including the length of the structure as well as processing etalon features to further enhance or shape the dispersion profiles. All these features can be substantially enhanced or exploited using various nonlinear effects including both the Kerr and Drude effects [14].

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